

TURBOSWITCH ULTRA-FAST HIGH VOLTAGE DIODE

MAIN PRODUCT CHARACTERISTICS

| | |
|----------------------|-------|
| $I_{F(AV)}$ | 8A |
| V_{RRM} | 1200V |
| $t_{rr}(\text{typ})$ | 50ns |
| $V_F(\text{max})$ | 2.0V |

FEATURES AND BENEFITS

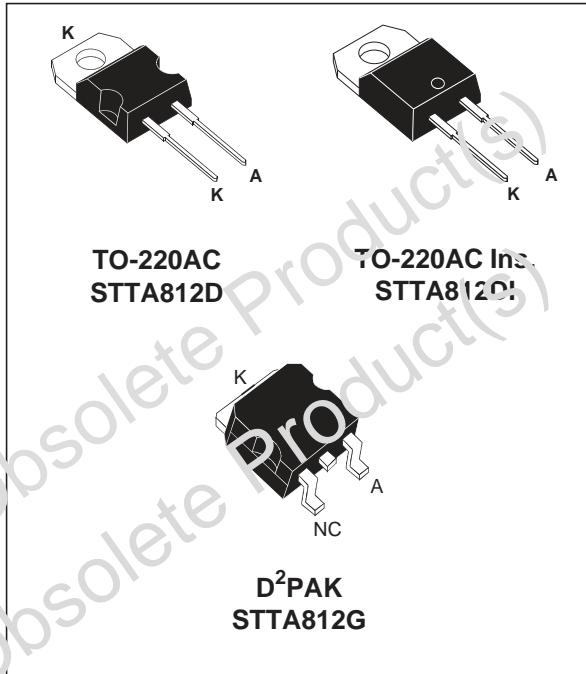
- ULTRA-FAST, SOFT RECOVERY.
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR.
- HIGH FREQUENCY AND/OR HIGH PULSED CURRENT OPERATION.
- HIGH REVERSE VOLTAGE CAPABILITY
- INSULATED PACKAGE : TO-220AC Ins.
Electrical insulation : 2500V_{RMS}
Capacitance : 7pF.

DESCRIPTION

TURBOSWITCH 1200V drastically cuts losses in all high voltage operations which require extremely fast, soft and noise-free power diodes. Due to their optimized switching performances they also highly decrease power losses in any associated switching IGBT or MOSFET in all "freewheel mode" operations.

ABSOLUTE RATINGS (limiting values)

| Symbole | Parameter | Value | Unit |
|--------------|----------------------------------------|------------------------------|------|
| V_{RRM} | Repetitive peak reverse voltage | 1200 | V |
| V_{RSM} | Non repetitive peak reverse voltage | 1200 | V |
| $I_{F(RMS)}$ | RMS forward current | TO-220AC/ D ² PAK | A |
| | | TO-220AC Ins. | A |
| I_{FRM} | Repetitive peak forward current | tp = 5 µs F = 5kHz square | A |
| I_{FSM} | Surge non repetitive forward current | tp = 10ms sinusoidal | A |
| T_{stg} | Storage temperature range | - 65 to + 150 | °C |
| T_j | Maximum operating junction temperature | 150 | °C |



They are particularly suitable in motor control circuitries, or in the primary of SMPS as snubber, clamping or demagnetizing diodes. They are also suitable for secondary of SMPS as high voltage rectifier diodes.

STTA812D/DI/G

THERMAL AND POWER DATA

| Symbol | Parameter | Conditions | Value | Unit |
|---------------|-------------------------------------------------------------------------|----------------------------------------------|-------------------------------------------|-----------|
| $R_{th(j-c)}$ | Junction to case thermal resistance | TO-220AC/D ² PAK TO-220AC Ins. | 2.3 3.3 | °C/W |
| P_1 | Conduction power dissipation $I_F(AV) = 8A \quad \delta = 0.5$ | TO-220AC/D ² PAK TO-220AC Ins. | $T_c = 105^\circ C$ $T_c = 85^\circ C$ | 19.5 W |
| P_{max} | Total power dissipation $P_{max} = P_1 + P_3 \quad (P_3 = 10\% P_1)$ | TO-220AC/D ² PAK TO-220AC Ins. | $T_c = 100^\circ C$ $T_c = 79^\circ C$ | 21.5 W |

STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test conditions | | Min | Typ | Max | Unit |
|----------|-------------------------|----------------------------|-------------------------------------------|-----|------|------------|----------|
| V_F * | Forward voltage drop | $I_F = 8A$ | $T_j = 25^\circ C$ $T_j = 125^\circ C$ | | 1.35 | 2.2 2.0 | V V |
| I_R ** | Reverse leakage current | $V_R = 0.8 \times V_{RRM}$ | $T_j = 25^\circ C$ $T_j = 125^\circ C$ | | 0.6 | 100 4 | μA mA |
| V_{to} | Threshold voltage | $I_p < 3.I_{AV}$ | $T_j = 125^\circ C$ | | | 1.57 | V |
| rd | Dynamic parameter | | | | | 54 | mΩ |

Test pulses : * $t_p = 380 \mu s, \delta < 2\%$

** $t_p = 5 ms, \delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_F(AV) + rd \times I_F^2(RMS)$$

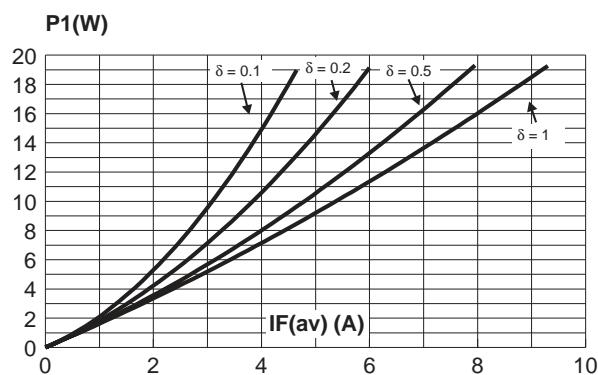
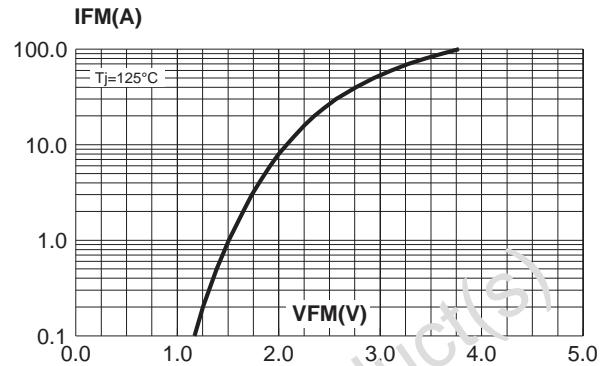
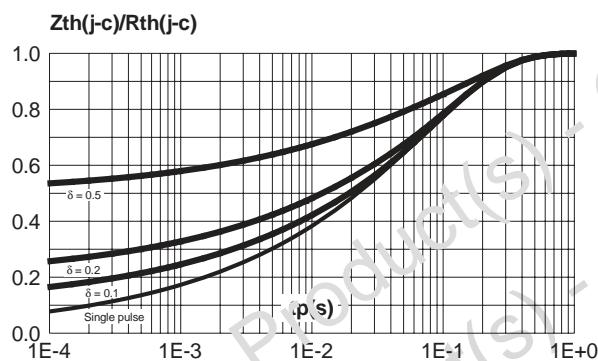
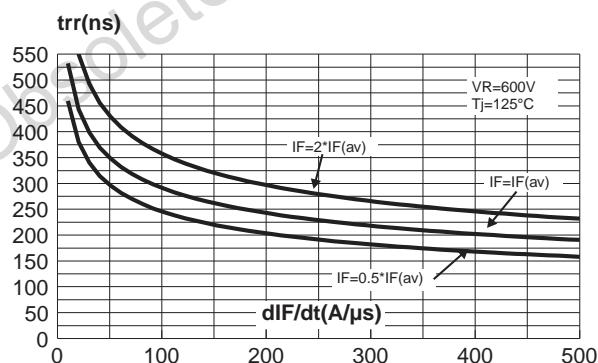
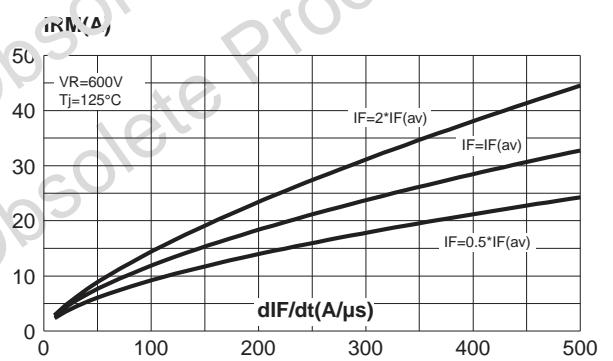
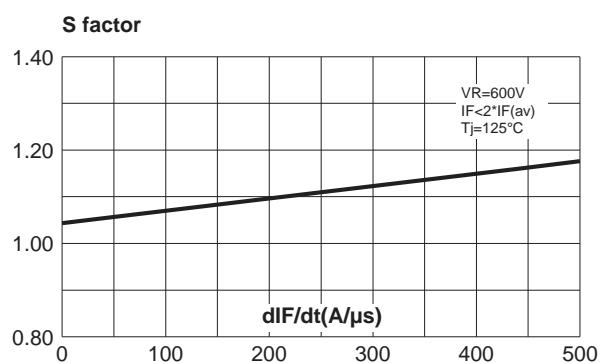
DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING

| Symbol | Parameter | Test conditions | Min | Typ | Max | Unit |
|----------|----------------------------------|--------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| t_{rr} | Reverse recovery time | $T_j = 25^\circ C$ $I_F = 0.5 A \quad I_R = 1A \quad Irr = 0.25A$ $I_F = 1 A \quad dI_F/dt = -50A/\mu s \quad V_R = 30V$ | | 50 | 100 | ns |
| i_{RM} | Maximum reverse recovery current | $T_j = 125^\circ C \quad V_R = 600V \quad I_F = 8A$ $dI_F/dt = -64 A/\mu s$ $dI_F/dt = -500 A/\mu s$ | | 25 | 12 | A |
| S factor | Softness factor | $T_j = 125^\circ C \quad V_R = 600V \quad I_F = 8A$ $dI_F/dt = -500 A/\mu s$ | | 1.2 | | - |

TURN-ON SWITCHING

| Symbol | Parameter | Test conditions | Min | Typ | Max | Unit |
|----------|-----------------------|----------------------------------------------------------------------------------------------|-----|-----|-----|------|
| t_{fr} | Forward recovery time | $T_j = 25^\circ C$ $I_F = 8 A, dI_F/dt = 64 A/\mu s$ measured at $1.1 \times V_{Fmax}$ | | | 900 | ns |
| V_{Fp} | Peak forward voltage | $T_j = 25^\circ C$ $I_F = 8A, dI_F/dt = 64 A/\mu s$ $I_F = 40A, dI_F/dt = 500 A/\mu s$ | | 45 | 35 | V |

Fig. 1: Conduction losses versus average current.**Fig. 2:** Forward voltage drop versus forward current (maximum values).**Fig. 3:** Relative variation of thermal impedance junction to case versus pulse duration.**Fig. 5:** Reverse recovery time versus dI_F/dt (90% confidence).**Fig. 4:** Peak reverse recovery current versus dI_F/dt (90% confidence).**Fig. 6:** Softness factor (tb/ta) versus dI_F/dt (typical values).

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Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference $T_j=125^\circ\text{C}$).

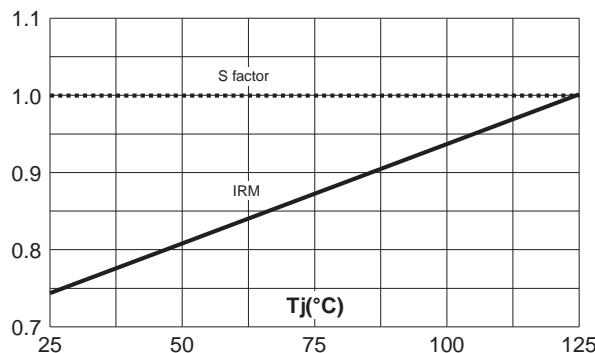


Fig.8: Transient peak forward voltage versus $\text{d}I_F/\text{dt}$ (90% confidence).

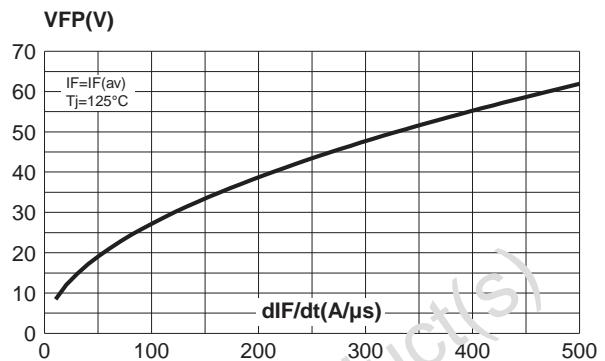
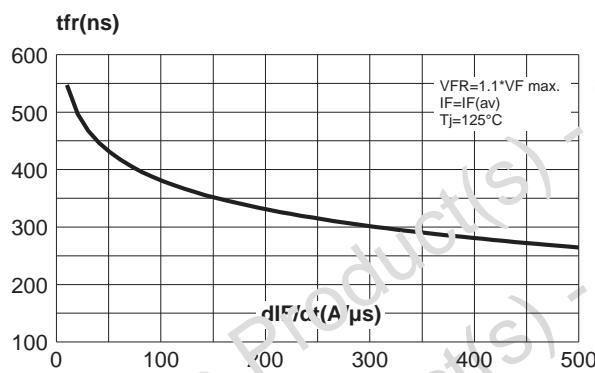
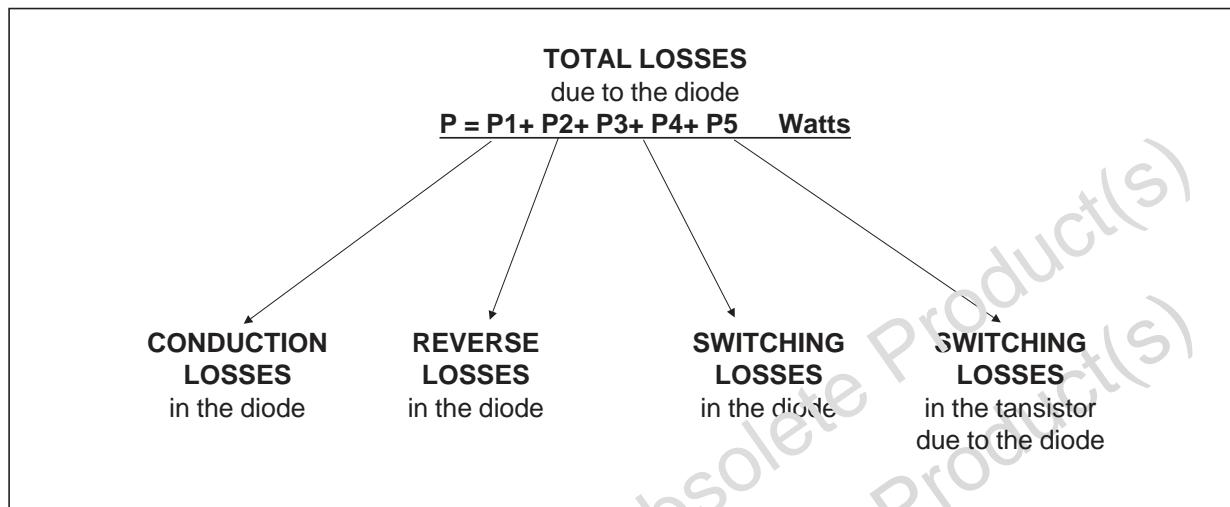
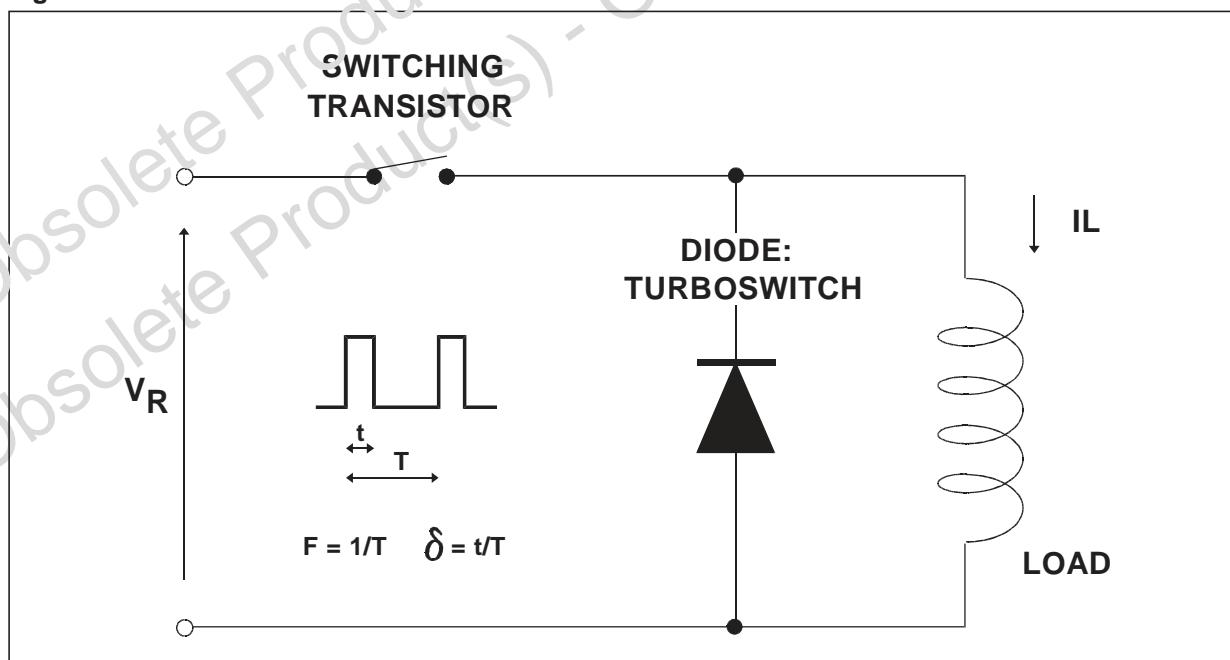


Fig. 9: Forward recovery time versus $\text{d}I_F/\text{dt}$ (90% confidence).



APPLICATION DATA

The 1200V TURBOSWITCH series has been designed to provide the lowest overall power losses in all high frequency or high pulsed current operations. In such applications (Fig A to D),the way of calculating the power losses is given below :

**Fig. A: "FREEWHEEL" MODE.**

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Fig. B: SNUBBER DIODE.

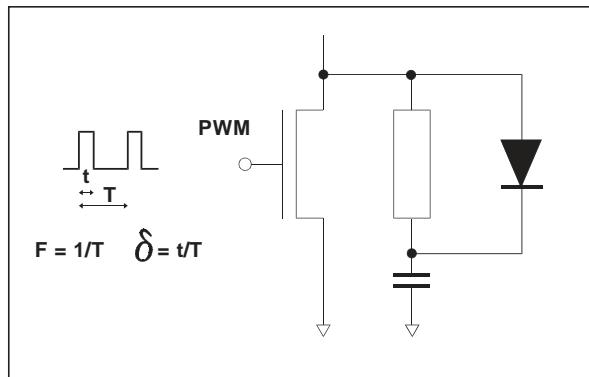


Fig. C: DEMAGNETIZING DIODE.

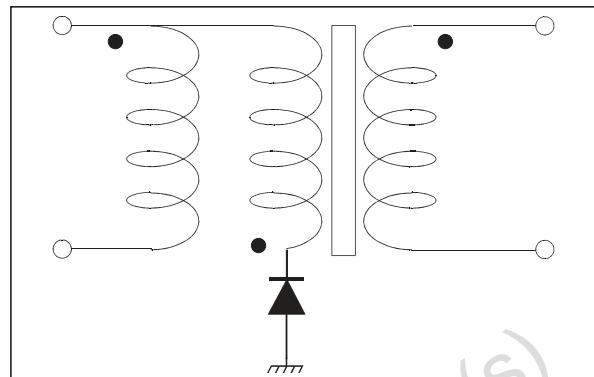
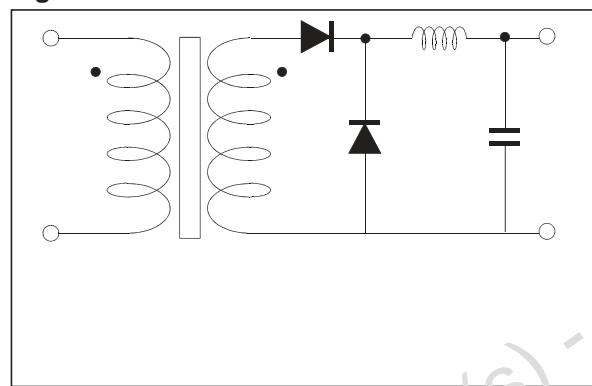
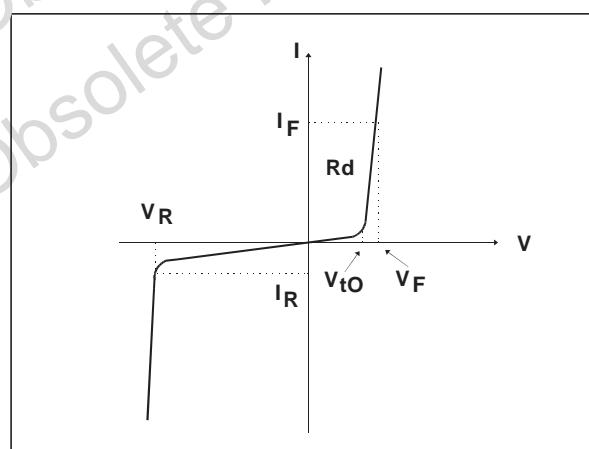


Fig. D: RECTIFIER DIODE.



STAT C & DYNAMIC CHARACTERISTICS . POWER LOSSES .

Fig. E: STATIC CHARACTERISTICS



Conduction losses :

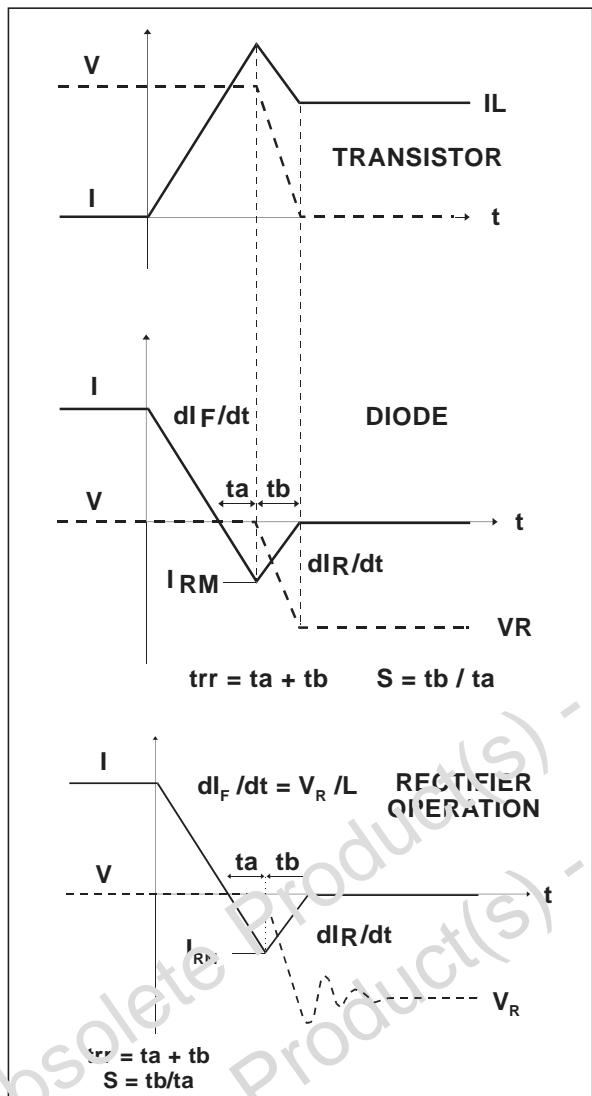
$$P1 = V_{t0} \cdot I_{F(AV)} + R_d \cdot I_F^2(\text{RMS})$$

Reverse losses :

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

APPLICATION DATA (Cont'd)

Fig. F: TURN-OFF CHARACTERISTICS



Turn-on losses :
(in the transistor, due to the diode)

$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F/dt}$$

Turn-off losses (in the diode) :

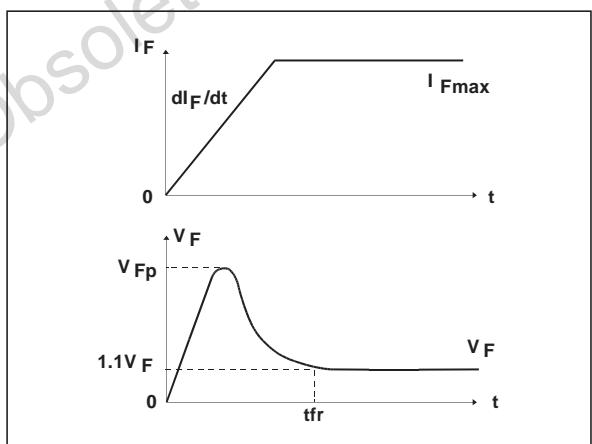
$$P3 = \frac{V_{f_r} \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt}$$

Turn-off losses :
(with non negligible serial inductance)

$$P3' = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt} + \frac{L \times I_{RM}^2 \times F}{2}$$

P3, P3' and P5 are suitable for power MOSFET and IGBT

Fig. G: TURN-ON CHARACTERISTICS

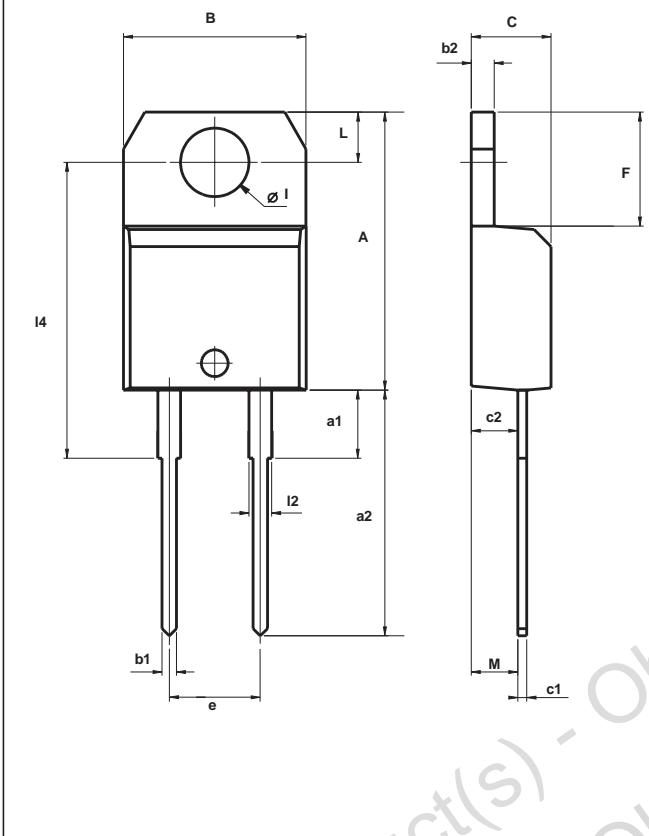


Turn-on losses :

$$P4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot tfr \cdot F$$

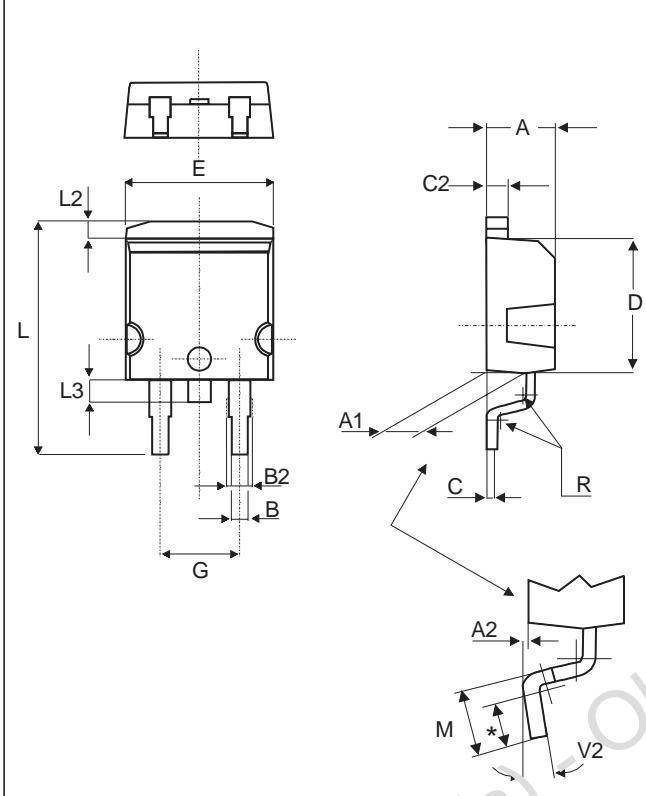
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PACKAGE DATA TO-220AC Ins.



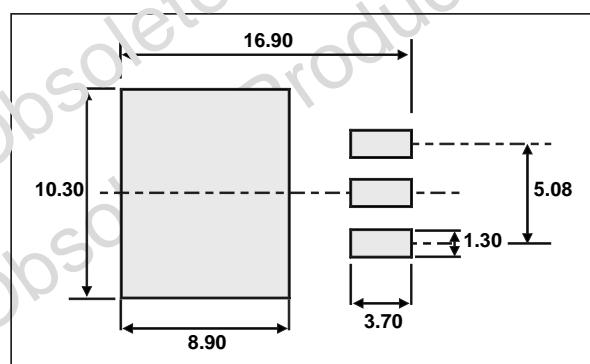
| REF. | DIMENSIONS | | | | | |
|------|-------------|-------|-------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 15.20 | | 15.90 | 0.598 | | 0.625 |
| a1 | | 3.75 | | | 0.147 | |
| a2 | 13.00 | | 14.00 | 0.511 | | 0.551 |
| B | 10.00 | | 10.40 | 0.393 | | 0.409 |
| b1 | 0.61 | | 0.88 | 0.024 | | 0.034 |
| b2 | 1.23 | | 1.32 | 0.048 | | 0.051 |
| C | 4.40 | | 4.60 | 0.173 | | 0.181 |
| c1 | 0.49 | | 0.70 | 0.019 | | 0.027 |
| c2 | 2.40 | | 2.72 | 0.094 | | 0.107 |
| e | 4.80 | | 5.40 | 0.189 | | 0.212 |
| F | 6.20 | | 6.60 | 0.244 | | 0.259 |
| I | 3.75 | | 3.85 | 0.147 | | 0.151 |
| I4 | 15.80 | 16.40 | 16.80 | 0.622 | 0.646 | 0.661 |
| L | 2.65 | | 2.95 | 0.104 | | 0.116 |
| I2 | 1.14 | | 1.70 | 0.044 | | 0.066 |
| M | | 2.60 | | | 0.102 | |

- Cooling method: by conduction (C)
- Recommended torque value: 0.8 m.N
- Maximum torque value: 1.0 m.N

PACKAGE DATA
D²PAK


The diagram illustrates the physical dimensions of the STTA812D/DI/G package. It includes three views: a top view showing leads E and G; a side view showing height L, lead thicknesses A, A1, A2, and C2, lead width B, lead height D, and lead pitch C; and a bottom view showing lead thicknesses A2, A1, and C2, lead width B, lead height D, lead pitch C, lead angle V2, lead thickness M, and lead height L3. A note at the bottom states: * FLAT ZONE NO LESS THAN 2mm.

| REF. | DIMENSIONS | | | |
|------|-------------|-------|------------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.40 | 4.60 | 0.173 | 0.181 |
| A1 | 2.49 | 2.69 | 0.098 | 0.106 |
| A2 | 0.03 | 0.23 | 0.001 | 0.009 |
| B | 0.70 | 0.93 | 0.027 | 0.037 |
| B2 | 1.14 | 1.70 | 0.045 | 0.067 |
| C | 0.45 | 0.60 | 0.017 | 0.024 |
| C2 | 1.23 | 1.36 | 0.048 | 0.054 |
| D | 8.95 | 9.35 | 0.352 | 0.368 |
| E | 10.00 | 10.40 | 0.393 | 0.409 |
| G | 4.88 | 5.28 | 0.192 | 0.208 |
| L | 5.00 | 15.85 | 0.590 | 0.624 |
| L2 | 1.27 | 1.40 | 0.050 | 0.055 |
| L3 | 1.40 | 1.75 | 0.055 | 0.069 |
| M | 2.40 | 3.20 | 0.094 | 0.126 |
| R | 0.40 typ. | | 0.016 typ. | |
| V2 | 0° | 8° | 0° | 8° |

FOOTPRINT DIMENSIONS (in millimeters)


STTA812D/DI/G

PACKAGE DATA

TO-220AC (JEDEC outline)

| REF. | DIMENSIONS | | | |
|---------|-------------|-------|------------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.40 | 4.60 | 0.173 | 0.181 |
| C | 1.23 | 1.32 | 0.048 | 0.051 |
| D | 2.40 | 2.72 | 0.094 | 0.107 |
| E | 0.49 | 0.70 | 0.019 | 0.027 |
| F | 0.61 | 0.88 | 0.024 | 0.034 |
| F1 | 1.14 | 1.70 | 0.044 | 0.065 |
| G | 4.95 | 5.15 | 0.194 | 0.202 |
| H2 | 10.00 | 10.40 | 0.393 | 0.409 |
| L2 | 16.40 typ. | | 0.645 typ. | |
| L4 | 13.00 | 14.00 | 0.511 | 0.551 |
| L5 | 2.05 | 2.95 | 0.104 | 0.116 |
| L6 | 15.25 | 15.75 | 0.600 | 0.620 |
| L7 | 6.20 | 6.60 | 0.244 | 0.259 |
| L9 | 3.50 | 3.93 | 0.137 | 0.154 |
| M | 2.6 typ. | | 0.102 typ. | |
| Diam. I | 3.75 | 3.85 | 0.147 | 0.151 |

- Cooling method: by conduction (C)
- Recommended torque value: 0.55 m.N
- Maximum torque value: 0.7 m.N

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|-----------|--------------------|--------|----------|---------------|
| STTA812L | STTA812D | TO-220AC | 1.86g | 50 | Tube |
| STTA812DI | STTA812DI | TO-220AC Ins. | 1.86g | 250 | Bulk |
| STTA812G | STTA812G | D ² PAK | 1.48g | 50 | Tube |
| STTA812G-TR | STTA812G | D ² PAK | 1.48g | 500 | Tape & reel |

- Epoxy meets UL94,V0

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